# Double counts in STIX's Caliste-SO detectors

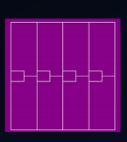
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PROGRESS ON EUV & X-RAY SPECTROSCOPY AND IMAGING II WROCŁAW – 17-19.11.2015

#### STIX & Caliste-SO

Caliste-SO – hybrid component integrating the sensor material and dedicated front-end electronics.



- Main parameters of STIX's
  - Energy range 4-150 keV
  - Energy resolution 1-15 keV (energy dependent)
  - Angular resolution 7 arcsec
  - Pointing accuracy 4 arcsec
  - Field of view 2°
  - Time resolution 0.1 s (statistics limited)
- Detector electronics module (DEM)
  - 32 CdTe sensors on Caliste-SO hybrids
  - Analog-to-digital converters
  - Data processing unit (IDPU)
  - Low-voltage/sensor bias power supplies

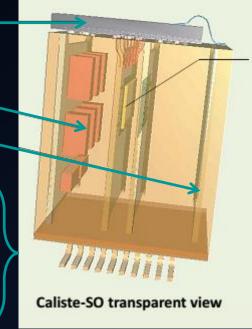
CdTe pixel detector

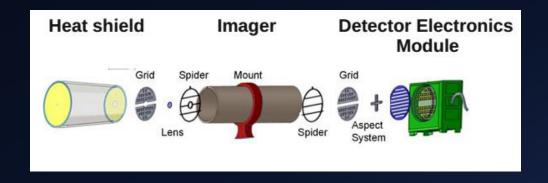
Passive filtering parts •

High voltage routing

Electrical SOP interface

- ASIC power supplies
- Sensor high bias voltage
- Slow control I/O
- Test injection
- Differential analog output





How does double counting will influence measured solar spectra?

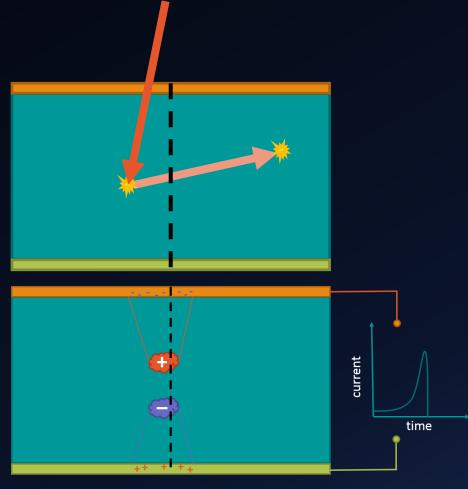
# Double counts

Double count - one photon simultaneously measured in more than one pixel

Two effects occur double counts:

1. Secondary photons ilumination

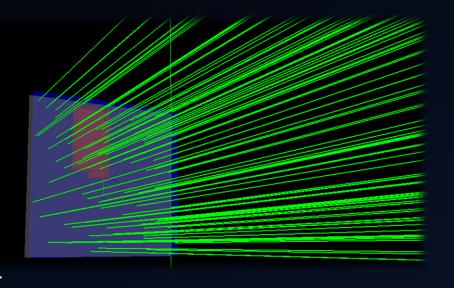
2. Charge sharing

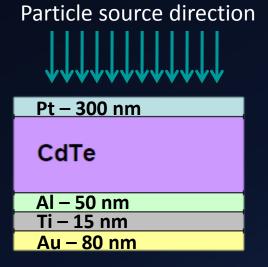


#### Geant4 simulation

- Source:
  - Monoenergetic photons
  - Energy from 4 to 150 keV with step 0.1
- Active volume:
  - whole cristal
- Photon beam covers entire detector area
- List of physics process:
  - Photons
    - Photoelectric effect
    - Compton scattering
    - Gamma conversion
    - Rayleigh scattering

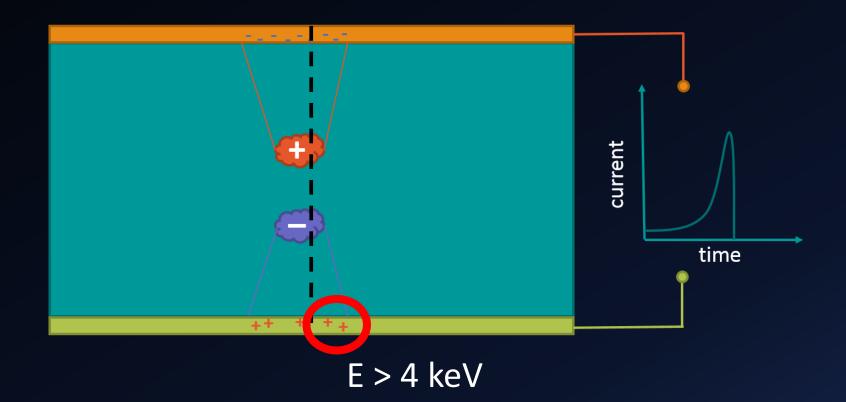
- Electrons
  - Multiple scattering
  - Ionization
  - Bremsstrahlung





#### STIX's threshold

STIX is measuring photons with energy more than 4 keV.



# Hole tailing

Measured lower energies

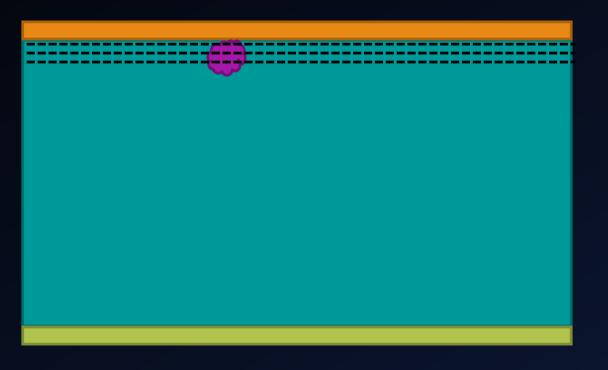


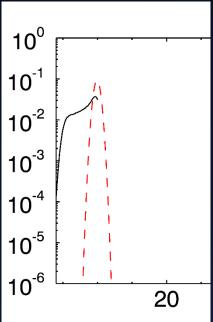
# Damage layer

Measured lower energies

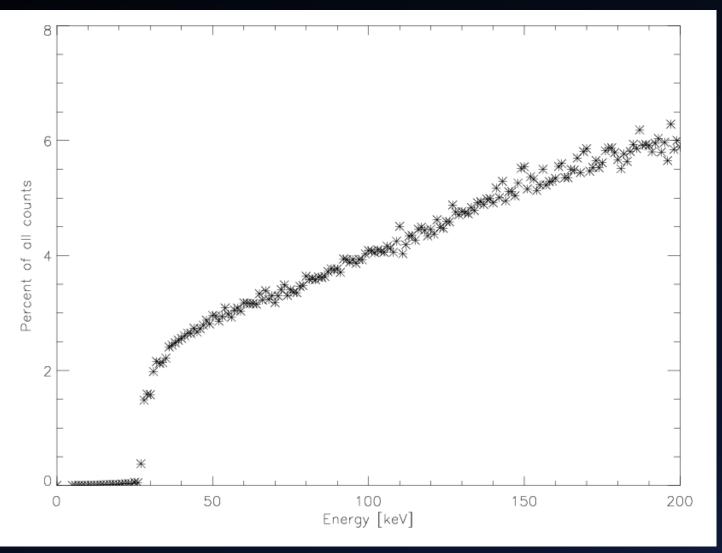
$$n_0 = n_0 (1 - e^{-x/\lambda_{entrance}})$$

 $n_0$  – number of electrons and holes initially created, x – absorption depth  $\lambda_{entrance}$  – damage layer thickness – 5  $\mu m$ 



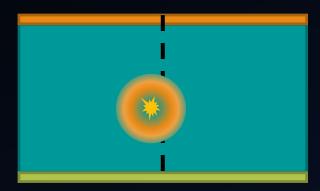


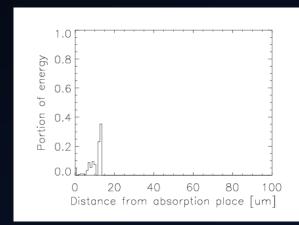
# 1. Secondary photon ilumination



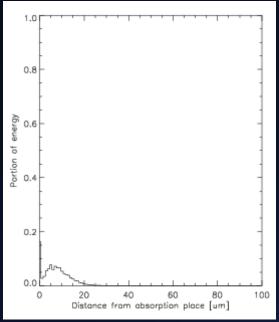
# Clouds shape

- Most part of electrons energies is deposited near the end of track.
- Sum of carriers clouds is symmetrica



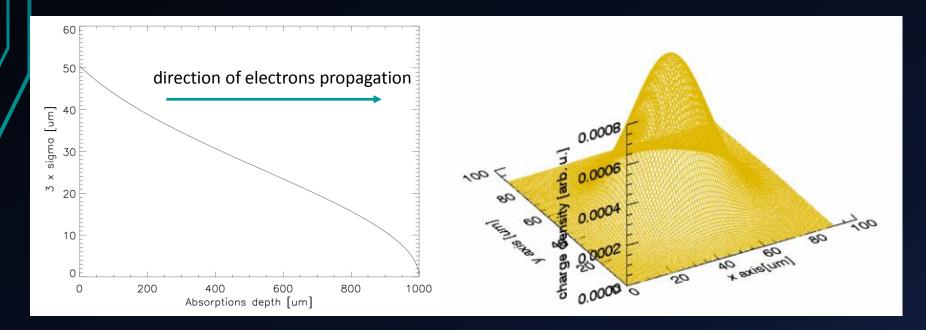






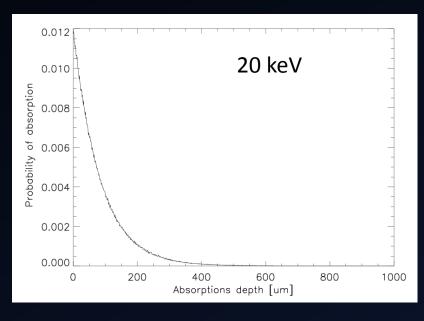
# Charge sharing

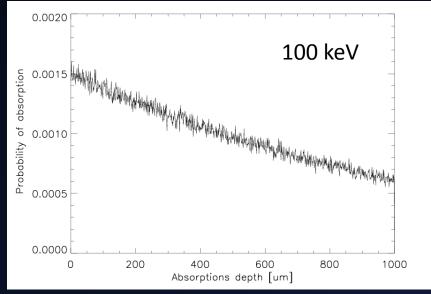
- Initial distribution: spherically symetric, normalised Gaussian.
- The expansion of a charge cloud is governed by Fick's second law.
- Electric field perpendicular to electrodes.



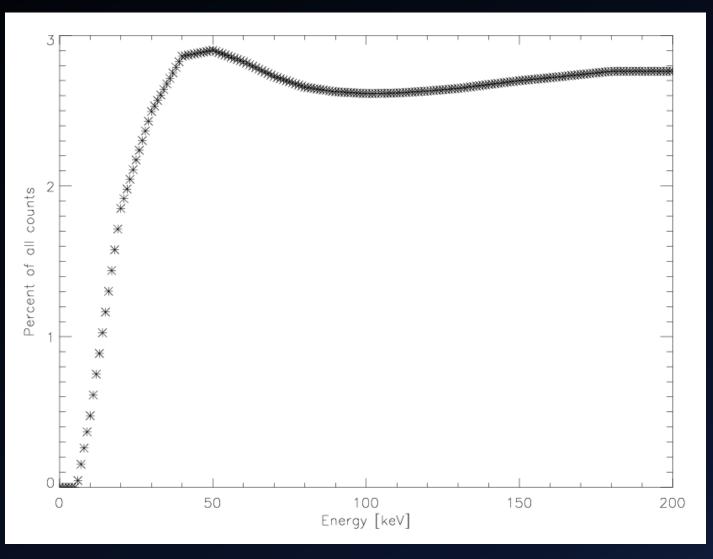
# Absorption depth

- We compute surface area, where double events occur, for each absorption depth.
- In next step, we divide this surface area by surface area of whole detector
  -> probability of double count.



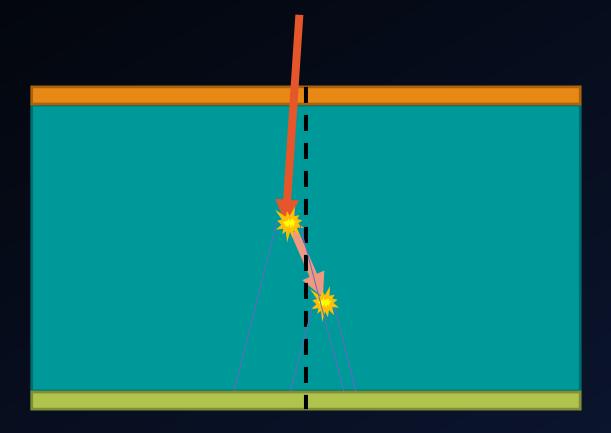


# 2. Charge sharing

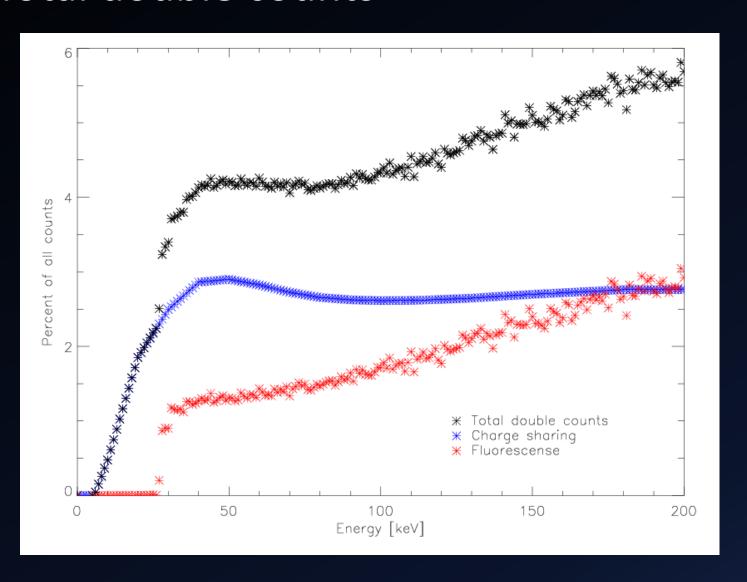


# Particular case

- This cases are twice counted.
- We remove such cases from fluorescent double counts.



# Total double counts



# Thank you

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